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**Product data sheet** 

#### 1. General description

The 74HC4049 is a hex inverter with over-voltage tolerant inputs. Inputs are overvoltage tolerant to 15 V. This enables the device to be used in HIGH-to-LOW level shifting applications.

#### 2. Features and benefits

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2 000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

#### 3. Ordering information

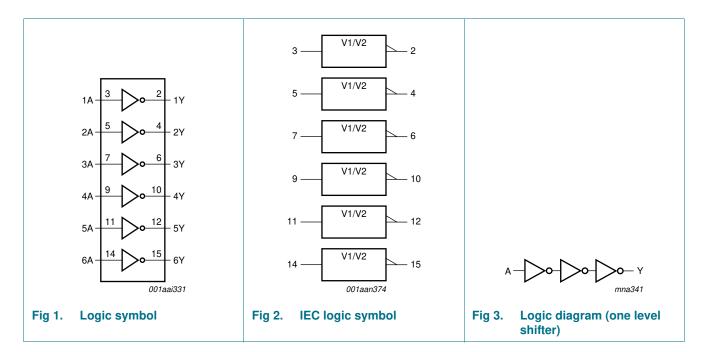
#### Table 1.Ordering information

Type number	Package									
	Temperature range	Name	Description	Version						
74HC4049N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4						
74HC4049D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1						
74HC4049DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1						
74HC4049PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1						



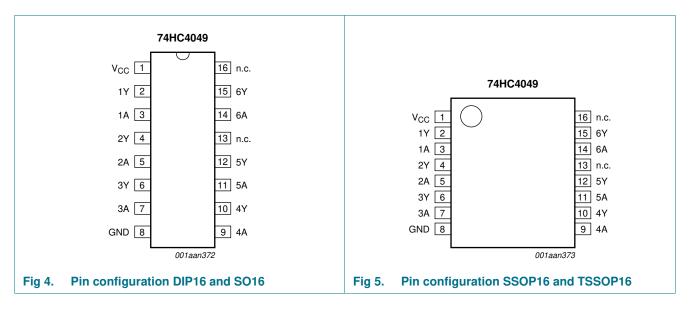
Hex inverting HIGH-to-LOW level shifter

#### 4. Functional diagram



### 5. Pinning information

#### 5.1 Pinning



#### Hex inverting HIGH-to-LOW level shifter

#### 5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
V <sub>CC</sub>	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output
1A to 6A	3, 5, 7, 9, 11, 14	input
GND	8	ground (0 V)
n.c.	13, 16	not connected

#### 6. Functional description

Table 3.   Function table [1]	
Input	Output
nA	nY
L	н
Н	L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

#### 7. Limiting values

#### Table 4.Limiting values

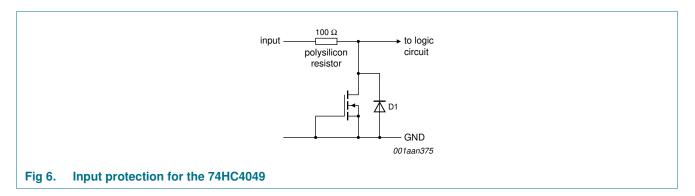
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					,
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
V <sub>IK</sub>	input clamping voltage		-0.5	+16	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 V$	-20	-	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC}$ + 0.5 V	-	±20	mA
lo	output current	$V_{O} = -0.5$ V to (V <sub>CC</sub> + 0.5 V)	-	±25	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-	-50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	DIP16 package	<u>[1]</u> -	750	mW
		SO16, SSOP16 and TSSOP16 packages	[2] _	500	mW

[1] For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

For SO16 package: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.
 For SSOP16 and TSSOP16 packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.

#### Hex inverting HIGH-to-LOW level shifter



### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	15	V
Vo	output voltage		0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}; \text{ V}_{I} = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 6.0 \text{ V}$	-	-	83	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 10.0 \text{ V}$	-	-	81	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 15.0 \text{ V}$	-	-	83	ns/V

### 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	itions T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = −40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.3	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.1	-	4.2	-	4.2	-	V
V <sub>IL</sub> LOW-level	$V_{CC} = 2.0 V$	-	0.7	0.5	-	0.5	-	0.5	V	
	input voltage	$V_{CC} = 4.5 V$	-	1.8	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.3	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_O$ = $-20~\mu\text{A};~V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_{O}$ = –5.2 mA; $V_{CC}$ = 6.0 V	5.48	-	-	5.34	-	5.2	-	V
74HC4049		All information provided in	this docume	ent is subject	to legal discla	aimers.		© NX	P B.V. 2013. All ri	ghts reserved

#### Hex inverting HIGH-to-LOW level shifter

#### Symbol Parameter Conditions T<sub>amb</sub> = 25 °C T<sub>amb</sub> = -40 °C to T<sub>amb</sub> = -40 °C to Unit +85 °C +125 °C Min Тур Max Min Max Min Max $V_{I} = V_{IH} \text{ or } V_{IL}$ V<sub>OL</sub> LOW-level output voltage $I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$ ۷ 0.1 0.1 0.1 \_ \_ \_ \_ $I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$ 0.1 0.1 0.1 ٧ ---- $I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$ V \_ \_ 0.1 \_ 0.1 0.1 \_ $I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ 0.26 0.33 0.4 ٧ \_ -\_ \_ $I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$ 0.26 0.33 0.4 ٧ ---- $V_I = V_{CC}$ or GND; I<sub>I</sub> input leakage ±0.1 ±1.0 μA \_ \_ \_ $\pm 1.0$ - $V_{CC} = 6.0 V$ current $V_{I} = 15 \text{ V}; V_{CC} = 2.0 \text{ V} \text{ to}$ ±0.5 ±5.0 ±5.0 \_ -\_ \_ μA 6.0 V $V_{I} = 15 \text{ V or GND}; I_{O} = 0 \text{ A};$ I<sub>CC</sub> supply current 2.0 20 40 μA -\_ \_ \_ $V_{CC} = 6.0 V$ Cı input 3.5 pF --\_ -\_ capacitance

#### Table 6. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

#### **10. Dynamic characteristics**

#### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see <u>Figure 8</u>.

Symbol Parameter		Conditions		T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = −40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit	
				Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation	nA to nY; see Figure 7	<u>[1]</u>								
	delay	$V_{CC} = 2.0 V$		-	28	85	-	105	-	130	ns
		$V_{CC} = 4.5 V$		-	10	17	-	21	-	26	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	8	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	8	14	-	18	-	22	ns
tt	transition	Yn; see Figure 7	[2]								
	time	$V_{CC} = 2.0 V$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$		-	6	13	-	16	-	19	ns

#### Hex inverting HIGH-to-LOW level shifter

Voltages	are referenced	d to GND (ground = 0 V); $C_L = 50$	) pF unl	ess oth	erwise	specified	l; for test ci	rcuit see	Figure 8.	
Symbol	Parameter	Conditions	T <sub>ar</sub>	<sub>nb</sub> = 25	°C		= –40 °C 85 °C		= –40 °C 125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Мах	
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF}; \text{ f} = 1 \text{ MHz};$ $V_I = \text{GND to } V_{\text{CC}}$ $(3)$	-	14	-	-	-	-	-	pF

#### Table 7. Dynamic characteristics ... continued

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).  $P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}{}^{2} \times f_{o})$  where:

 $f_i$  = input frequency in MHz;

fo = output frequency in MHz;

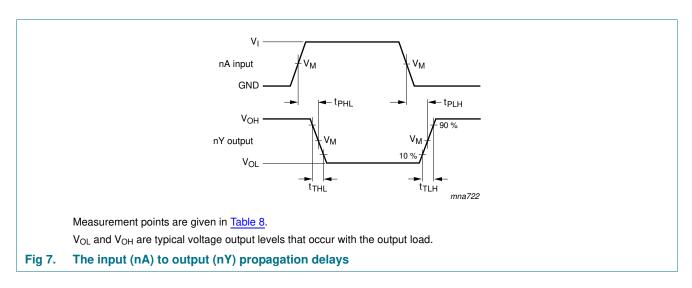
 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

#### 11. Waveforms



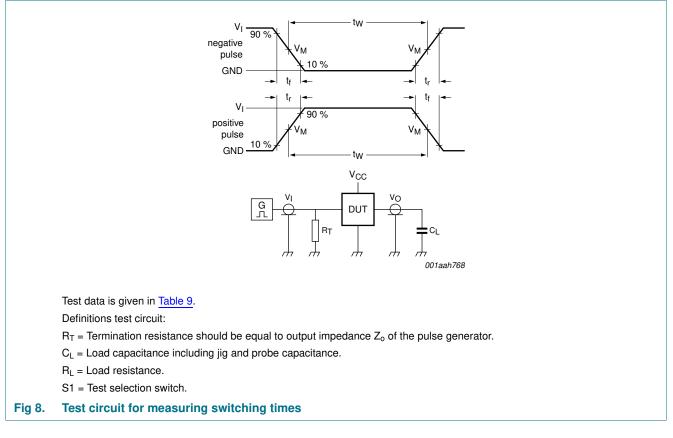
#### Table 8. **Measurement points**

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC4049	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>

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## 74HC4049

#### Hex inverting HIGH-to-LOW level shifter



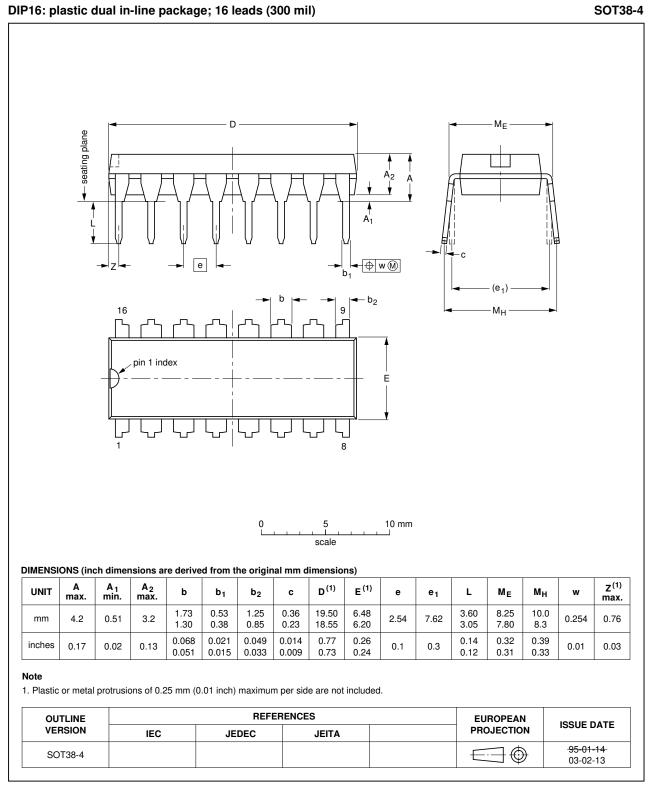
#### Table 9. Test data

Туре	Input		Load	Test
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
74HC4049	V <sub>CC</sub>	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

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Hex inverting HIGH-to-LOW level shifter

#### 12. Package outline



#### Fig 9. Package outline SOT38-4 (DIP16)

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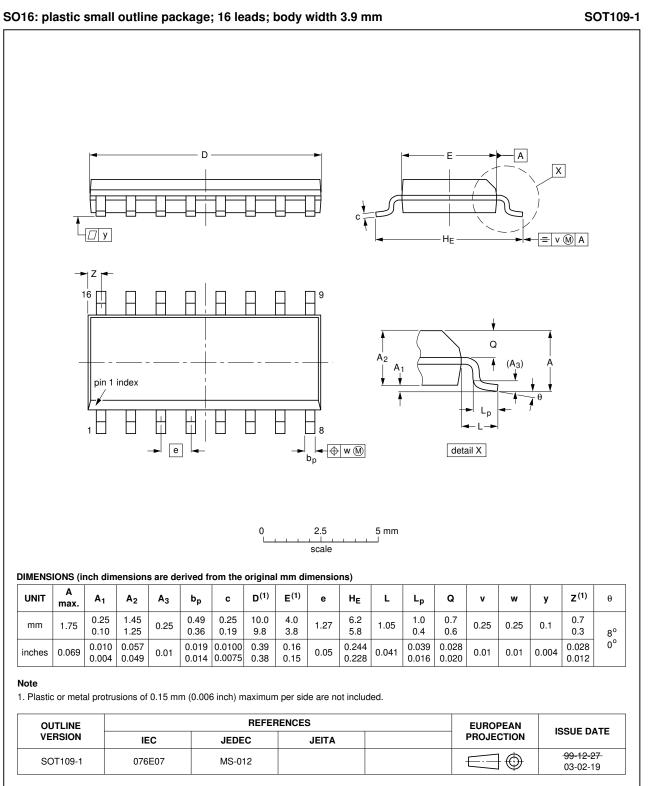
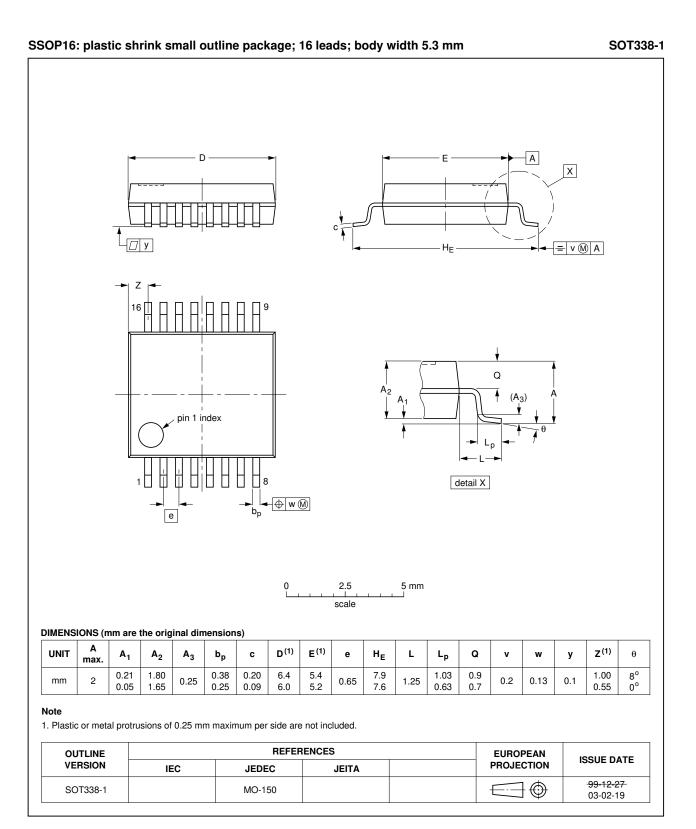


Fig 10. Package outline SOT109-1 (SO16)

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#### Fig 11. Package outline SOT338-1 (SSOP16)

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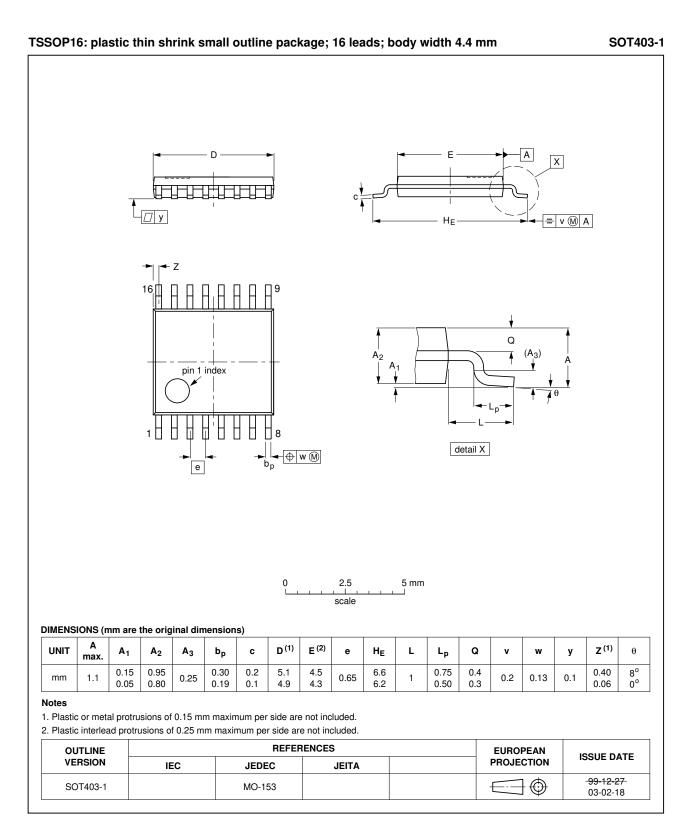


Fig 12. Package outline SOT403-1 (TSSOP16)

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#### Hex inverting HIGH-to-LOW level shifter

### **13. Abbreviations**

Table 10.	Abbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

### 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC4049 v.6	20130108	Product data sheet	-	74HC4049 v.5
Modifications:	<ul> <li>New gener</li> </ul>	al description.		
74HC4049 v.5	20120803	Product data sheet	-	74HC4049 v.4
Modifications:	<ul> <li>Measurem</li> </ul>	ent points added to figure	7 (errata).	
74HC4049 v.4	20111212	Product data sheet	-	74HC4049 v.3
74HC4049 v.3	20101230	Product data sheet	-	74HC4049_CNV v.2
74HC4049_CNV v.2	19970827	Product specification	-	-

#### Hex inverting HIGH-to-LOW level shifter

#### 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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#### Hex inverting HIGH-to-LOW level shifter

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